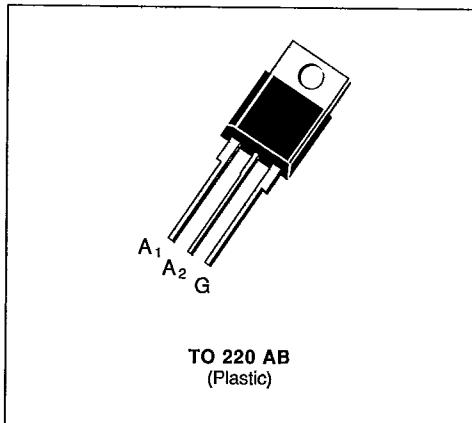


**S G S-THOMSON****TRIACS**

- GLASS PASSIVATED CHIP
- EXCELLENT  $(dv/dt)_c > 10 \text{ V}/\mu\text{s}$
- $I_{GT}$  SPECIFIED IN FOUR QUADRANTS
- AVAILABLE IN INSULATED VERSION →  
BTA SERIES (INSULATING VOLTAGE  
2500 V<sub>RMS</sub>) OR IN UNINSULATED VERSION  
→ BTB SERIES
- UL RECOGNIZED FOR BTA SERIES (E81734)

**DESCRIPTION**

New range suited for applications such as phase control and static switching.

**ABSOLUTE RATINGS (limiting values)**

Symbol	Parameter	Value	Unit
$I_{TRMS}$	RMS on-state Current (360° conduction angle)	8	A
$I_{TSM}$	Non Repetitive Surge Peak on-state Current ( $T_i$ initial = 25 °C - Half sine wave)	t = 8.3 ms	A
		t = 10 ms	
$I^2t$	$I^2t$ Value for Fusing	32	$\text{A}^2\text{s}$
$di/dt$	Critical Rate of Rise of on-state Current (1)	Repetitive $F = 50 \text{ Hz}$	$\text{A}/\mu\text{s}$
		Non Repetitive	
$T_{stg}$ $T_j$	Storage and Operating Junction Temperature Range	- 40 to 150 - 40 to 110	°C °C

Symbol	Parameter	BTA/BTB 08-					Unit
		200B	400B	600B	700B	800B	
$V_{DRM}$	Repetitive Peak off-state Voltage (2)	200	400	600	700	800	V

(1)  $I_a = 1 \text{ A}$     $di/dt = 1 \text{ A}/\mu\text{s}$ (2)  $T_j = 110 \text{ °C}$ .**THERMAL RESISTANCES**

Symbol	Parameter	Value	Unit
$R_{th (j-a)}$	Junction to Ambient	60	°C/W
$R_{th (j-c)} \text{ DC}$	Junction to Case for DC	4.3	°C/W
$R_{th (j-c)} \text{ AC}$	Junction to Case for 360° Conduction Angle ( $F = 50 \text{ Hz}$ )	3.2	°C/W

**GATE CHARACTERISTICS** (maximum values)

$P_{GM} = 40 \text{ W}$  ( $t_p = 10 \mu\text{s}$ )       $I_{GM} = 4 \text{ A}$  ( $t_p = 10 \mu\text{s}$ )  
 $P_G(\text{AV}) = 1 \text{ W}$        $V_{GM} = 16 \text{ V}$  ( $t_p = 10 \mu\text{s}$ )

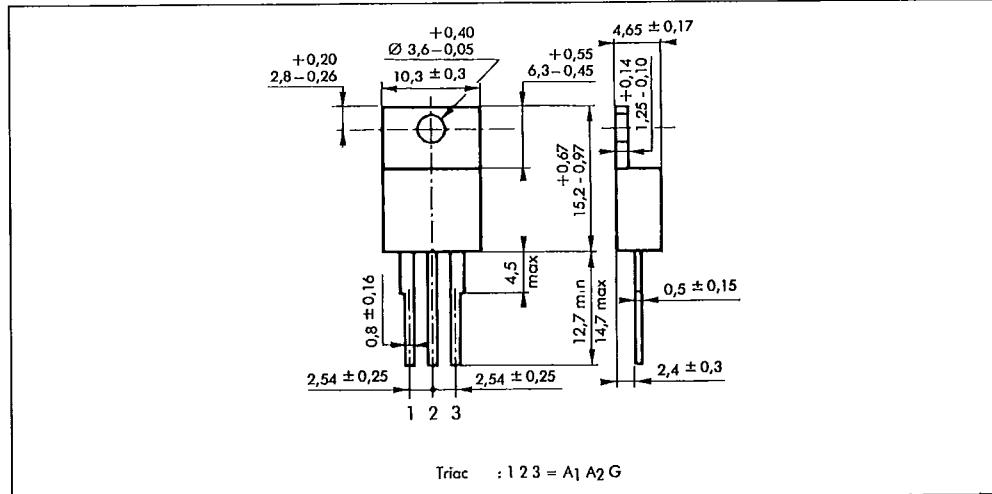
T-25-15

**ELECTRICAL CHARACTERISTICS**

Symbol	Test Conditions			Quadrants	Min..	Typ.	Max.	Unit
$I_{GT}$	$T_j = 25^\circ\text{C}$	$V_D = 12 \text{ V}$	$R_L = 33 \Omega$	I-II-III			50	mA
	Pulse Duration > 20 $\mu\text{s}$			IV			100	
$V_{GT}$	$T_j = 25^\circ\text{C}$	$V_D = 12 \text{ V}$	$R_L = 33 \Omega$	I-II-III-IV			1.5	V
$V_{GD}$	$T_j = 110^\circ\text{C}$	$V_D = V_{DRM}$	$R_L = 3.3 \text{ k}\Omega$	I-II-III-IV	0.2			V
$I_H^*$	$T_j = 25^\circ\text{C}$	$I_T = 100 \text{ mA}$	Gate Open				50	mA
$I_L$	$T_j = 25^\circ\text{C}$	$V_D = 12 \text{ V}$	$I_G = 200 \text{ mA}$	I-III-IV		50		mA
	Pulse Duration > 20 $\mu\text{s}$			II		100		
$V_{TM}^*$	$T_j = 25^\circ\text{C}$	$I_{TM} = 11 \text{ A}$	$t_p = 10 \text{ ms}$				1.75	V
$I_{DRM}^*$	$V_{DRM}$ Specified		$T_j = 25^\circ\text{C}$				0.01	mA
			$T_j = 110^\circ\text{C}$				0.5	
$dv/dt^*$	$T_j = 110^\circ\text{C}$	Gate Open			250	500		$\text{V}/\mu\text{s}$
$(dv/dt)_c^*$	$T_C = 75^\circ\text{C}$	$V_D = V_{DRM}$	$I_T = 11 \text{ A}$		10			$\text{V}/\mu\text{s}$
$(dv/dt)_c$	$(dv/dt)_c = 3.5 \text{ A}/\text{ms}$							
$t_{gt}$	$T_j = 25^\circ\text{C}$	$V_D = V_{DRM}$	$I_T = 11 \text{ A}$	I-II-III-IV		2		$\mu\text{s}$
* For either polarity of electrode A <sub>2</sub> voltage with reference to electrode A <sub>1</sub> .								

**PACKAGE MECHANICAL DATA**

TO 220 AB Plastic



Cooling method : by conduction (method C)

Marking : type number

Weight : 2 g.

T-25-15

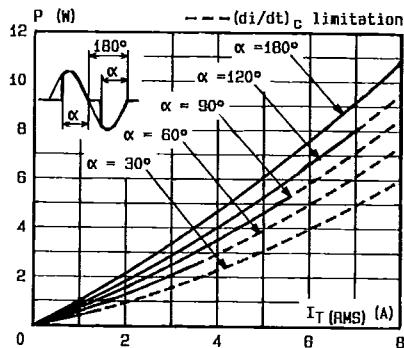
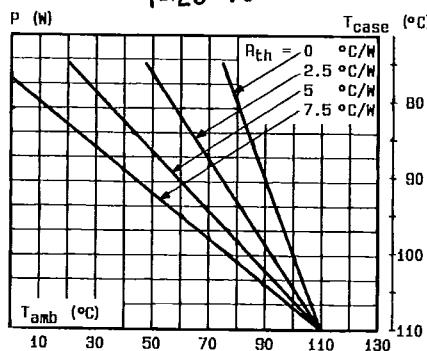
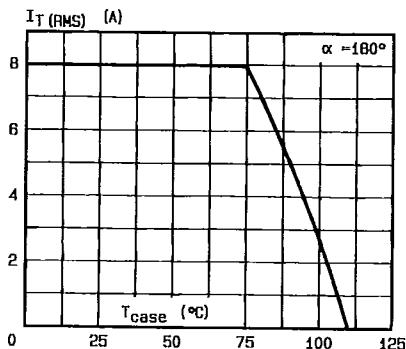
Fig.1 - Maximum mean power dissipation versus RMS on-state current ( $f = 60$  Hz).Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{\text{amb}}$  and  $T_{\text{case}}$ ) for different thermal resistances heatsink + contact.

Fig.3 - RMS on-state current versus case temperature.

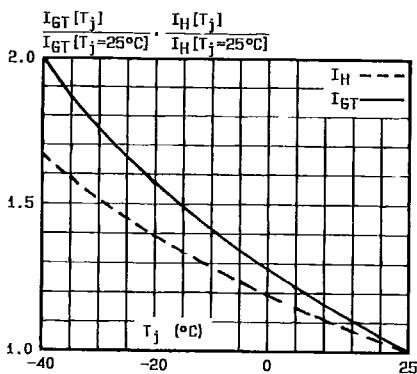


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

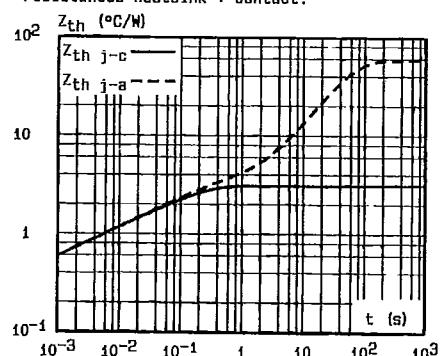


Fig.4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

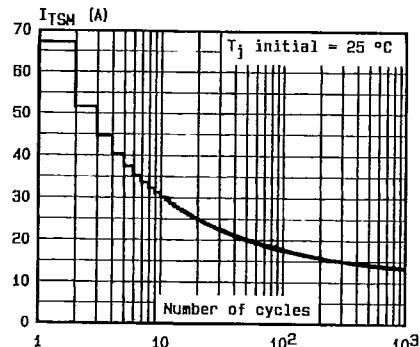


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

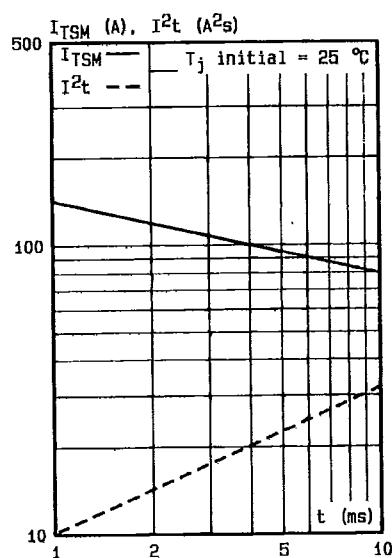


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

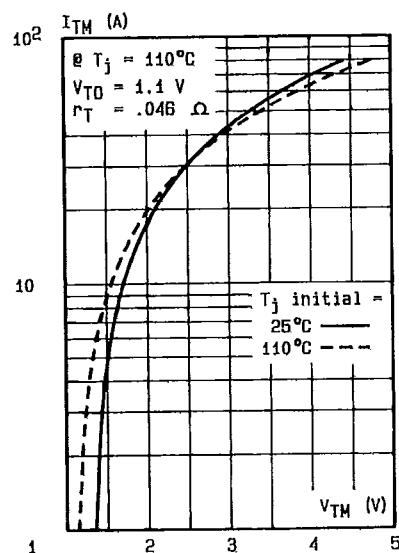


Fig.8 - On-state characteristics (maximum values).